

## High Bandwidth Potato Chip

### FEATURES:

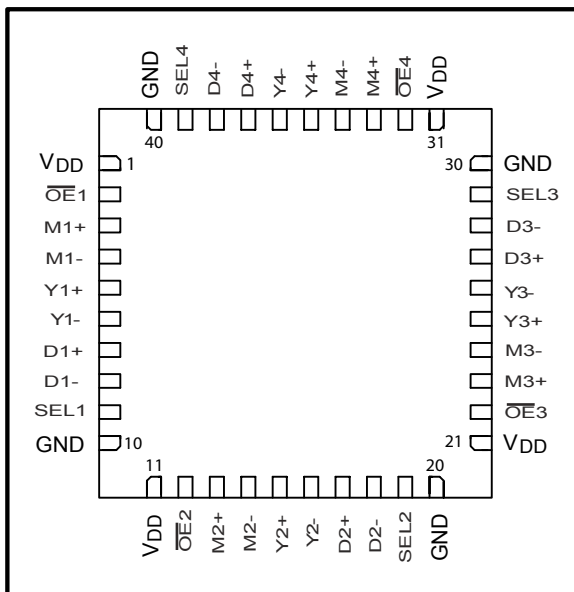
- Patented technology
- High signal -3db passing bandwidth at 1GHz
- Near-Zero propagation delay
- VCC = 1.65V to 3.6V
- Ultra-Low Quiescent Power: 0.1μA typical
- Ideally suited for low power applications
- Industrial operating temperature: -40°C to +85°C
- Available in 40pin 5mm x 5mm QFN package

### DESCRIPTION:

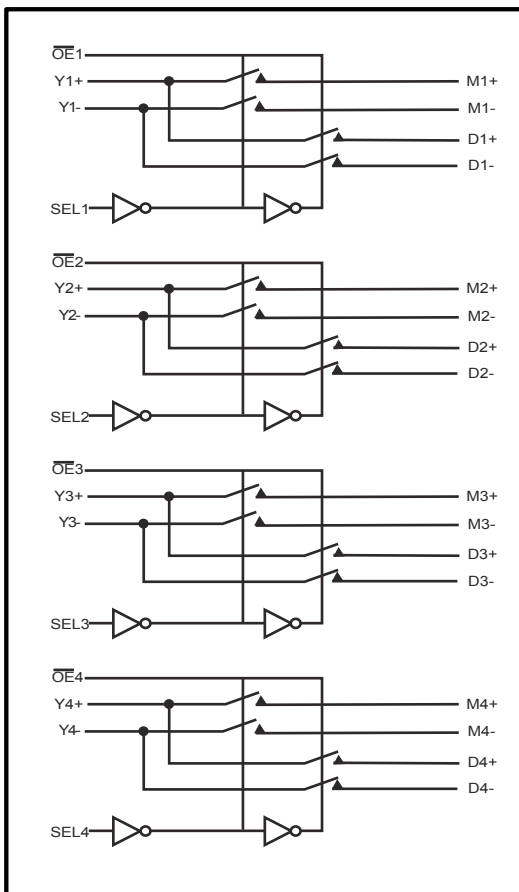
Potato Semiconductor's PO3B402A is designed for world top performance using submicron CMOS technology to achieve GHz high bandwidth.

The PO3B402A is a 4-Port 2-channel, 2:1 Multiplexer /Demultiplexer with 3-state outputs. The switch introduces no additional ground bounce noise or propagation delay.

### Pin Configuration



### Block Diagram



### Truth Table

| SELn | $\overline{OE}n$ | Yn+  | Yn-  |
|------|------------------|------|------|
| X    | H                | Hi-Z | Hi-Z |
| L    | L                | Mn+  | Mn-  |
| H    | L                | Dn+  | Dn-  |

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### Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

|                                              |                           |
|----------------------------------------------|---------------------------|
| Storage Temperature .....                    | -65°C to +150°C           |
| Ambient Temperature with Power Applied ..... | -40°C to +85°C            |
| Supply Voltage to Ground Potential .....     | -0.5V to +4.6V            |
| DC Input Voltage .....                       | -0.5V to +V <sub>CC</sub> |
| DC Output Current.....                       | 120mA                     |
| Power Dissipation.....                       | 0.5W                      |

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### DC Electrical Characteristics, 3.3V Supply

(Over the Operating Range, T<sub>A</sub> = -40°C to +85°C, V<sub>CC</sub> = 3.3V ±10%)

| Parameters       | Description                   | Test Conditions                                                                      | Min. | Typ. | Max. | Units |
|------------------|-------------------------------|--------------------------------------------------------------------------------------|------|------|------|-------|
| V <sub>IH</sub>  | Input HIGH Voltage            | Guaranteed Logic HIGH Level                                                          | 2.0  |      |      | V     |
| V <sub>IL</sub>  | Input LOW Voltage             | Guaranteed Logic LOW Level                                                           |      |      | 0.8  |       |
| I <sub>IH</sub>  | Input HIGH Current            | V <sub>CC</sub> = Max., V <sub>IN</sub> = V <sub>CC</sub>                            |      |      | ±1   | μA    |
| I <sub>IL</sub>  | Input LOW Current             | V <sub>CC</sub> = Max., V <sub>IN</sub> = GND                                        |      |      | ±1   |       |
| I <sub>OZH</sub> | High Impedance Output Current | 0 ≤ Y, I <sub>n</sub> ≤ V <sub>CC</sub>                                              |      |      | ±1   |       |
| R <sub>ON</sub>  | Switch On-Resistance          | V <sub>CC</sub> = Min., V <sub>IN</sub> = 0.0V,<br>I <sub>ON</sub> = -48 mA or -64mA |      | 14   | 18   | Ω     |
|                  |                               | V <sub>CC</sub> = Min., V <sub>IN</sub> = V <sub>CC</sub> , I <sub>ON</sub> = -15 mA |      | 16   | 20   |       |

### DC Electrical Characteristics, 2.5V Supply

(Over Operating Range, T<sub>A</sub> = -40°C to +85°C, V<sub>CC</sub> = 2.5V ± 10%)

| Parameters       | Description            | Test Conditions                                                                        | Min. | Typ. | Max.                  | Units |
|------------------|------------------------|----------------------------------------------------------------------------------------|------|------|-----------------------|-------|
| V <sub>IH</sub>  | Input HIGH Voltage     | Guaranteed Logic HIGH Level                                                            | 1.8  |      | V <sub>CC</sub> + 0.3 | V     |
| V <sub>IL</sub>  | Input LOW Voltage      | Guaranteed Logic LOW Level                                                             | -0.3 |      | 0.8                   |       |
| I <sub>IH</sub>  | Input HIGH Current     | V <sub>CC</sub> = Max., V <sub>IN</sub> = V <sub>CC</sub>                              |      |      | ±1                    | μA    |
| I <sub>IL</sub>  | Input LOW Current      | V <sub>CC</sub> = Max., V <sub>IN</sub> = GND                                          |      |      | ±1                    |       |
| I <sub>OZH</sub> | High Impedance Current | 0 ≤ Y, I <sub>n</sub> ≤ V <sub>CC</sub>                                                |      |      | ±1                    |       |
| R <sub>ON</sub>  | Switch On Resistance   | V <sub>CC</sub> = Min., V <sub>IN</sub> = 0.0V,<br>I <sub>ON</sub> = -48mA             |      | 18   | 22                    | Ω     |
|                  |                        | V <sub>CC</sub> = Min., V <sub>IN</sub> = V <sub>CC</sub> ,<br>I <sub>ON</sub> = -15mA |      | 18   | 22                    |       |

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### Power Supply Characteristics

| Symbol                | Description                    | Test Conditions (1)                                           | Min | Typ        | Max      | Unit      |
|-----------------------|--------------------------------|---------------------------------------------------------------|-----|------------|----------|-----------|
| <b>I<sub>cc</sub></b> | Quiescent Power Supply Current | V <sub>cc</sub> =Max, V <sub>in</sub> =V <sub>cc</sub> or GND | -   | <b>0.1</b> | <b>3</b> | <b>uA</b> |

**Notes:**

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V<sub>cc</sub> = 3.3V, 25°C ambient.
3. This parameter is guaranteed but not tested.
4. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
5. V<sub>oH</sub> = V<sub>cc</sub> – 0.6V at rated current

### Capacitance (T<sub>A</sub> = 25°C f = 1 MHz)

| Parameters       | Description                    | Test Conditions      | Typ. | Units |
|------------------|--------------------------------|----------------------|------|-------|
| C <sub>IN</sub>  | Input Capacitance              | V <sub>IN</sub> = 0V | 3.0  | pF    |
| C <sub>OFF</sub> | Port I Capacitance, Switch OFF |                      | 5.0  |       |
| C <sub>ON</sub>  | Switch Capacitance, Switch ON  |                      | 10.0 |       |

### Dynamic Electrical Characteristics Over the Operating Range

(T<sub>A</sub> = -40° to +85°, V<sub>CC</sub> = 3.3V ± 10%)

| Parameter         | Description    | Test Condition        | Typ. | Units |
|-------------------|----------------|-----------------------|------|-------|
| X <sub>TALK</sub> | Crosstalk      | R <sub>L</sub> = 100Ω | -60  | dB    |
| O <sub>IRR</sub>  | Off-Isolation  | R <sub>L</sub> = 100Ω | -60  |       |
| BW                | -3dB Bandwidth | R <sub>L</sub> = 100Ω | 1    | GHz   |

### Switching Characteristics over 3.3V Operating Range

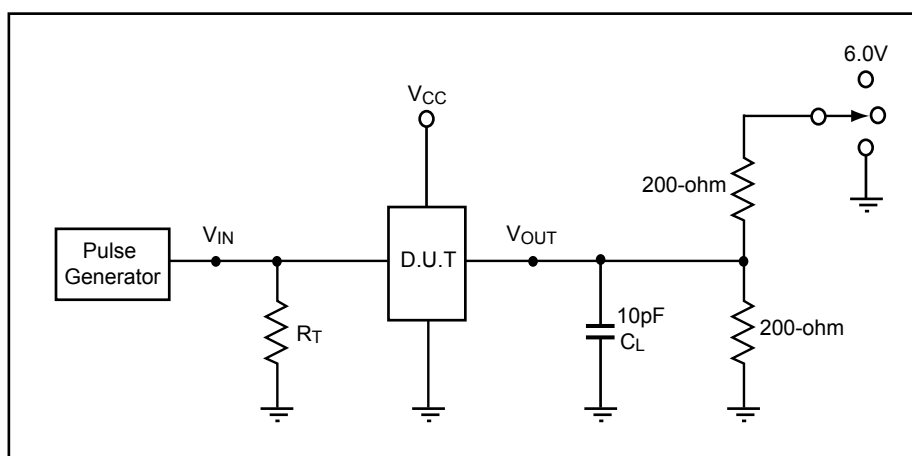
| Parameters                           | Description       | Conditions       | Max. | Units |
|--------------------------------------|-------------------|------------------|------|-------|
| t <sub>PLH</sub><br>t <sub>PHL</sub> | Propogation Delay | See Test Diagram | 0.3  | ns    |
| t <sub>PZH</sub><br>t <sub>PZL</sub> | Bus Enable Time   | See Test Diagram | 2.0  |       |
| t <sub>PHZ</sub><br>t <sub>PLZ</sub> | Bus Disable Time  |                  | 3.0  |       |

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### Switching Characteristics over 2.5V Operating Range

| Parameters             | Description       | Conditions       | Max. | Units |
|------------------------|-------------------|------------------|------|-------|
| $t_{PLH}$<br>$t_{PHL}$ | Propagation Delay | See Test Diagram | 0.3  | ns    |
| $t_{PZH}$<br>$t_{PZL}$ | Bus Enable Time   | See Test Diagram | 2.0  |       |
| $t_{PHZ}$<br>$t_{PLZ}$ | Bus Disable Time  |                  | 3.0  |       |

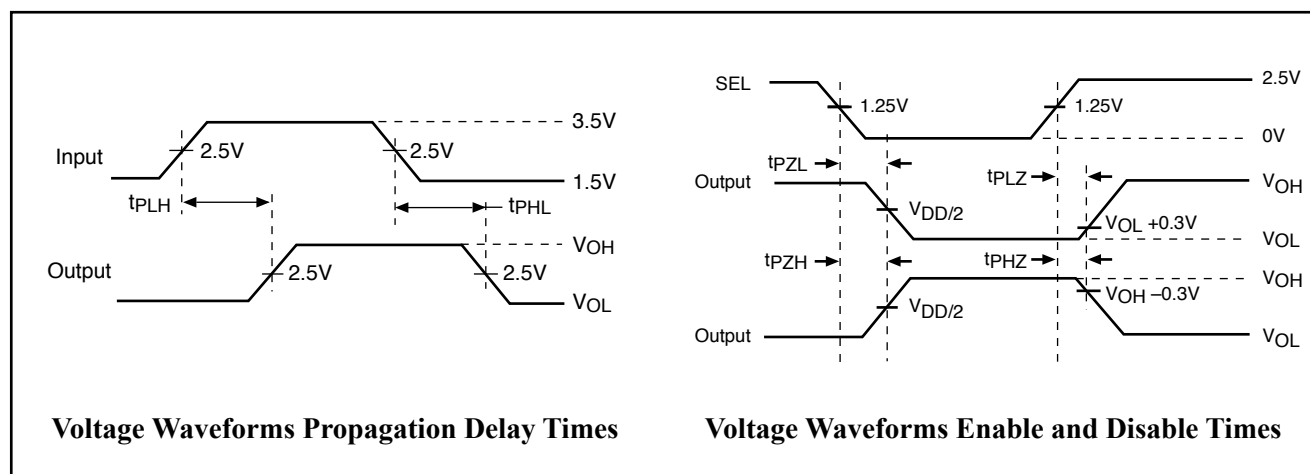
### Test Circuit for Electrical Characteristics



### Switch Positions

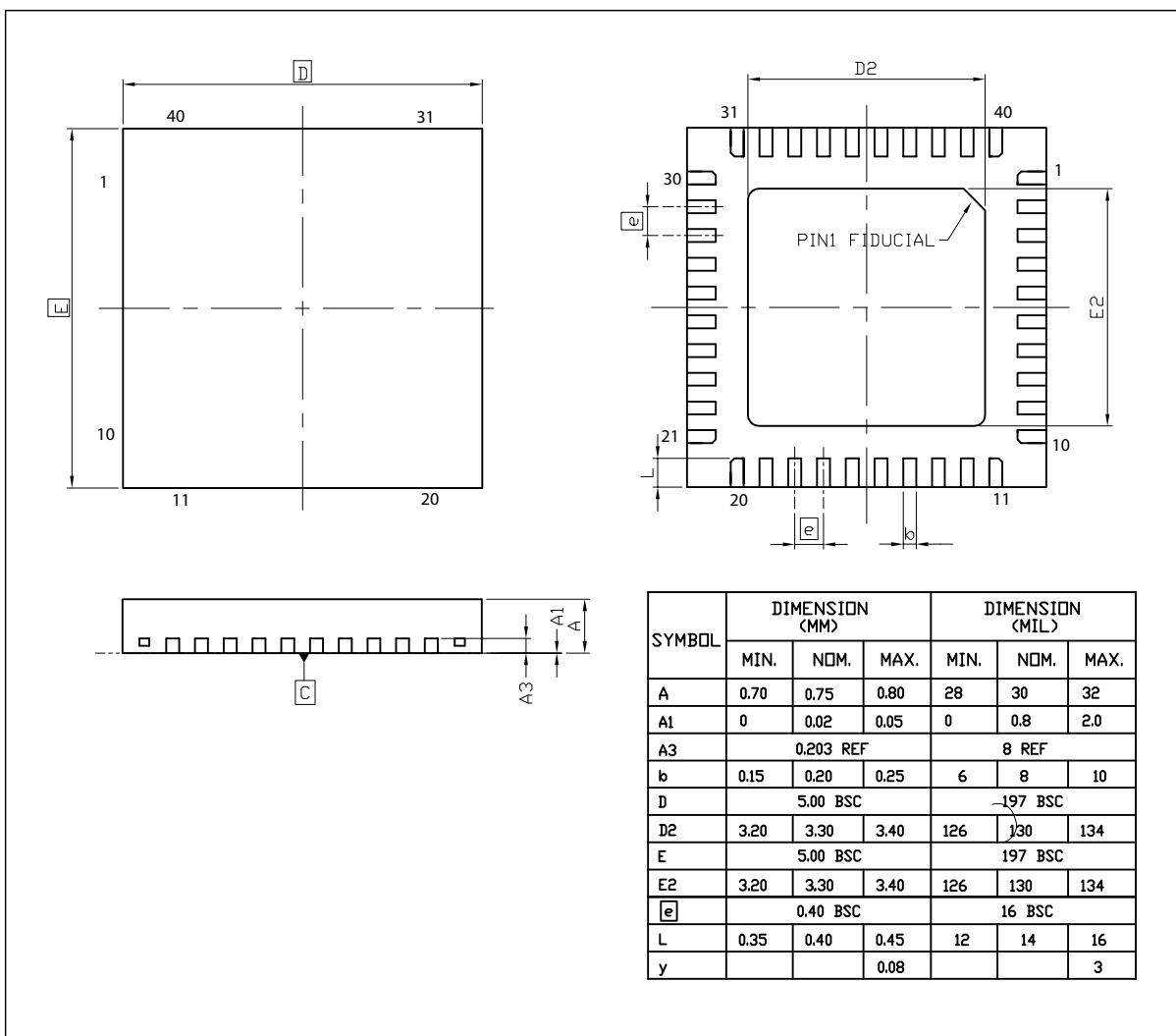
| Test                  | Switch |
|-----------------------|--------|
| $t_{PLZ}$ , $t_{PZL}$ | 6.0V   |
| $t_{PHZ}$ , $t_{PZH}$ | GND    |
| Prop Delay            | Open   |

### Switching Waveforms



## High Bandwidth Potato Chip

### Packaging Mechanical Drawing: 40 pin QFN





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### Ordering Information

| Ordering Code | Package    |               |                 | Top-Marking | T <sub>A</sub> |
|---------------|------------|---------------|-----------------|-------------|----------------|
| PO3B402AQFR   | 40-pin QFN | Tape and reel | Pb-free & Green | PO3B402AQF  | -40°C to 85°C  |